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December 2013

FCD380N60E

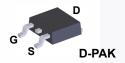
N-Channel SuperFET[®] II Easy-Drive MOSFET 600 V, 10.2 A, 380 m Ω

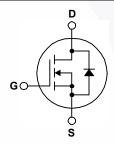
Features

- 650 V @ T_{.1} = 150°C
- Typ. $R_{DS(on)}$ = 320 m Ω
- Ultra Low Gate Charge (Typ. Q_q = 34 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 97 pF)
- · 100% Avalanche Tested
- · An Integrated Gate Resistor
- · RoHS Compliant

Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET easy-drive series offers slightly slower rise and fall times compared to the SuperFET II MOSFET series. Noted by the "E" part number suffix, this family helps manage EMI issues and allows for easier design implementation. For faster switching in applications where switching losses must be at an absolute minimum, please consider the SuperFET II MOSFET series.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter		FCD380N60E	Unit
V_{DSS}	Drain to Source Voltage			600	V
V	Cata ta Cauraa Valtaga	- DC		±20	V
V _{GSS}	Gate to Source Voltage	- AC	(f > 1 Hz)	±30	V
	Drain Current	- Continuous (T _C = 25°C)		10.2	Α
ID	Diain Current	- Continuous (T _C = 100°C)		6.4	A
I _{DM}	Drain Current	- Pulsed	- Pulsed (Note 1)		Α
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	211.6	mJ
I _{AR}	Avalanche Current (Note 1)		(Note 1)	2.3	Α
E _{AR}	Repetitive Avalanche Energy (Note 1)		(Note 1)	1.06	mJ
du/dt	MOSFET dv/dt			100	\//pa
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	20	V/ns
D	Device Discipation	(T _C = 25°C)		106	W
P_{D}	Power Dissipation	- Derate Above 25°C		0.85	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds 300				

Thermal Characteristics

Symbol	Parameter FCD380I		Unit	
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max. 1.18			
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	100	°C/W	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCD380N60E	FCD380N60E	DPAK	Tape and Reel	330 mm	16 mm	2500 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
D\/	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	600	-	-	V
BV _{DSS} Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 150^{\circ}\text{C}$	650	-	-	\ \	
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 10 mA, Referenced to 25°C	-	0.67	-	V/°C
BV _{DS}	Drain to Source Avalanche Breakdown Voltage	V _{GS} = 0 V, I _D = 10 A	-	700	-	٧
ı	Zero Gate Voltage Drain Current	V _{DS} = 480 V, V _{GS} = 0 V	-	-	5	
I _{DSS}	Zeio Gate Voltage Dialii Cuitelit	$V_{DS} = 480 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	-	20	μA
I _{GSS}	Gate to Body Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V	-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2.5	-	3.5	V
R _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$	-	0.32	0.38	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 20 \text{ V}, I_{D} = 5 \text{ A}$	-	10	-	S

Dynamic Characteristics

•						
C _{iss}	Input Capacitance	V 05.V.V 0.V	-	1330	1770	pF
C _{oss}	Output Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz	-	945	1260	pF
C _{rss}	Reverse Transfer Capacitance	1 = 1 1/11/12	-	60	90	pF
C _{oss}	Output Capacitance	$V_{DS} = 380 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	25	-	pF
C _{oss(eff.)}	Effective Output Capacitance	$V_{DS} = 0 \text{ V to } 480 \text{ V}, V_{GS} = 0 \text{ V}$	-	97	-	pF
Q _{g(tot)}	Total Gate Charge at 10V	V _{DS} = 380 V, I _D = 5 A,	-	34	45	nC
Q_{gs}	Gate to Source Gate Charge	V _{GS} = 10 V	-	5.3	-	nC
Q_{gd}	Gate to Drain "Miller" Charge	(Note 4)	-	13	-	nC
ESR	Equivalent Series Resistance	f = 1 MHz	-	6	-	Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		-	17	44	ns
t _r	Turn-On Rise Time	$V_{DD} = 380 \text{ V}, I_D = 5 \text{ A},$	-	9	28	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	64	138	ns
t _f	Turn-Off Fall Time	(Note 4)	-	10	30	ns

Drain-Source Diode Characteristics

IS	Maximum Continuous Drain to Source Diod	Maximum Continuous Drain to Source Diode Forward Current		-	10.2	Α
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	30.6	Α
V_{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _{SD} = 5 A	-	-	1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _{SD} = 5 A,	-	240		ns
Q _{rr}	Reverse Recovery Charge	$dI_F/dt = 100 A/\mu s$	-	3	-	μС

Notes:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. I_{AS} = 2.3 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C.
- 3. I $_{SD}$ \leq 5.1 A, di/dt \leq 200 A/ μ s, V $_{DD}$ \leq BV $_{DSS}$, starting T $_{J}$ = 25°C.
- Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

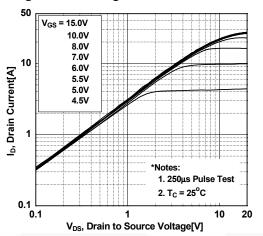


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

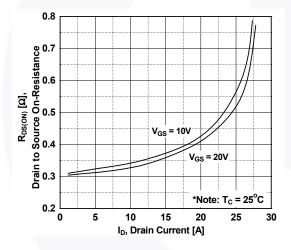


Figure 5. Capacitance Characteristics

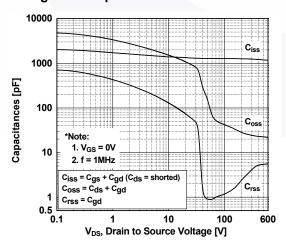


Figure 2. Transfer Characteristics

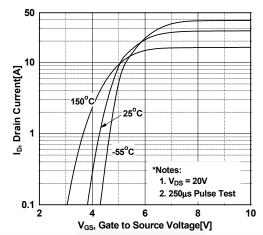


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

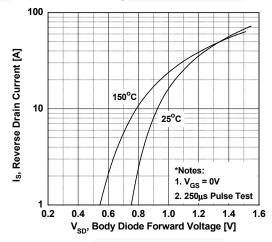
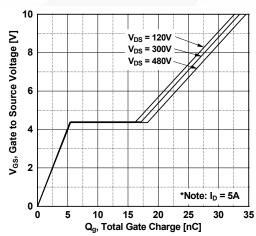


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

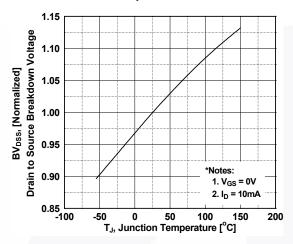


Figure 9. Maximum Safe Operating Area

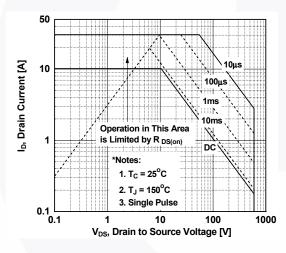


Figure 11. Eoss vs. Drain to Source Voltage

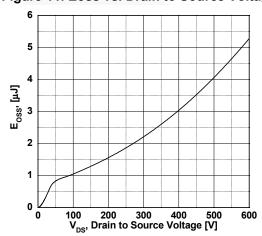


Figure 8. On-Resistance Variation vs. Temperature

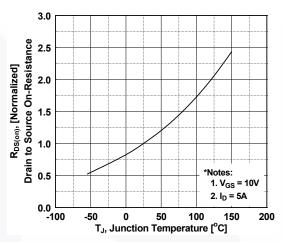
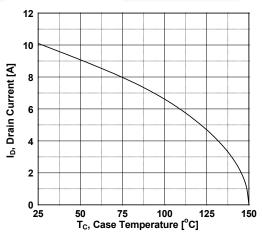
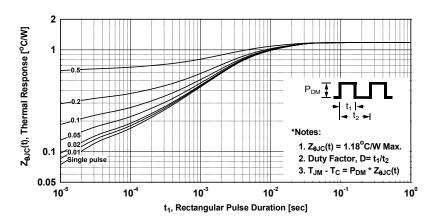


Figure 10. Maximum Drain Current vs. Case Temperature



Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve



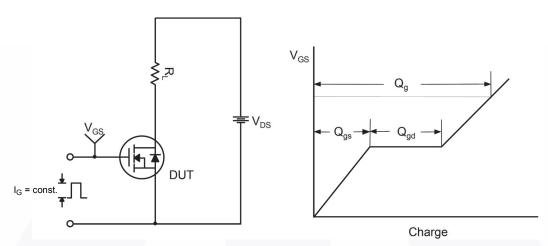


Figure 13. Gate Charge Test Circuit & Waveform

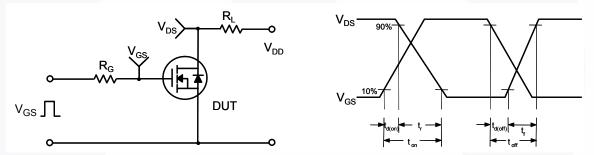


Figure 14. Resistive Switching Test Circuit & Waveforms

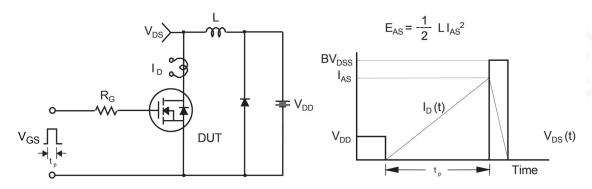


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms

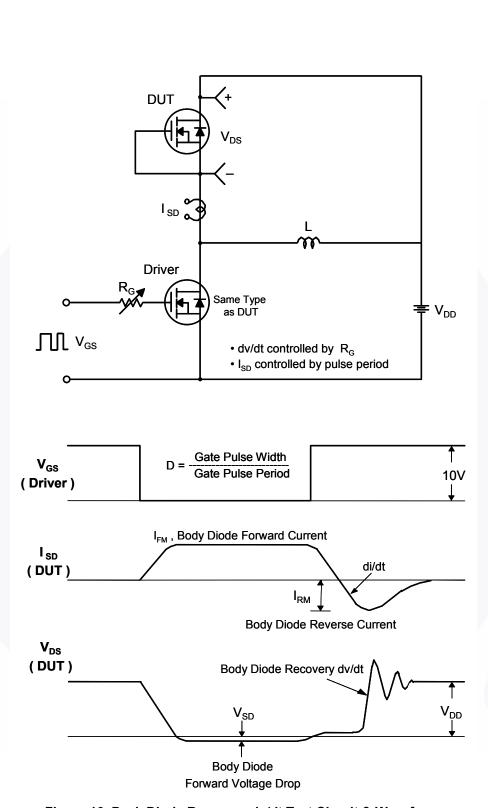


Figure 16. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

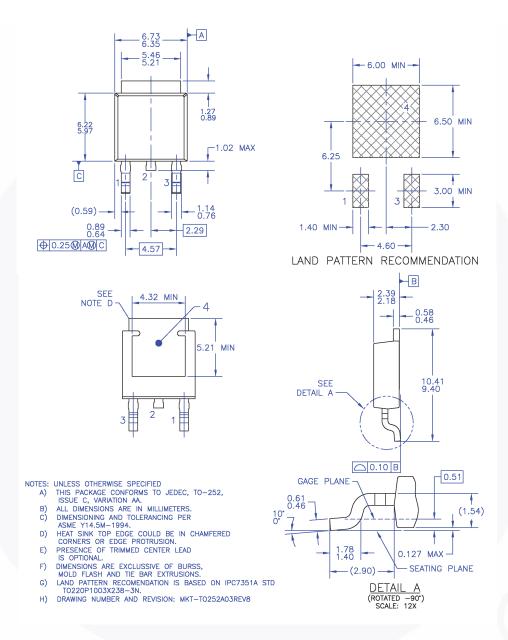


Figure 17. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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